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**PATENT APPLICATION**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Attn: OIPE

Ryoji HOSHI et al.

Group Art Unit: 1722

Application No.: 10/525,244

Docket No.: 122810

Filed: February 22, 2005

For: SINGLE CRYSTAL, SINGLE CRYSTAL WAFER, EPITAXIAL WAFER, AND  
METHOD OF GROWING SINGLE CRYSTAL

**REQUEST FOR CORRECTION OF PALM RECORDS**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Attached is a photocopy of the corrected filing receipt on which errors have been corrected in red. These errors are being brought to the attention of the Patent and Trademark Office so that it may correct its records.

Respectfully submitted,

William P. Berridge  
Registration No. 30,024

Mario A. Costantino  
Registration No. 33,565

WPB:MAC/jeh

Date: December 1, 2006

**OLIFF & BERRIDGE, PLC**  
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**Alexandria, Virginia 22320**  
**Telephone: (703) 836-6400**

DEPOSIT ACCOUNT USE AUTHORIZATION Please grant any extension necessary for entry; Charge any fee due to our Deposit Account No. 15-0461
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KAM

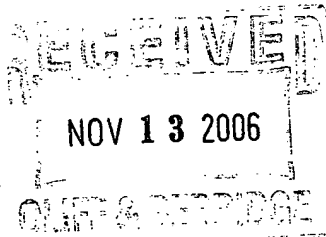


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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/525,244	02/22/2005	1722	900	122810	5	20	2

25944  
OLIFF & BERRIDGE, PLC  
P.O. BOX 19928  
ALEXANDRIA, VA 22320



CONFIRMATION NO. 5373

## CORRECTED FILING RECEIPT



\*OC000000021169480\*

Date Mailed: 11/09/2006

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

## Applicant(s)

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## Assignment For Published Patent Application

Shin-Etsu Handotai Co., ~~ETD~~ Tokyo, JAPAN  
Ltd.,

**Power of Attorney:** The patent practitioners associated with Customer Number 25944.

## Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP03/11443 09/08/2003

## Foreign Applications

JAPAN 2002-267563 09/13/2002

If Required, Foreign Filing License Granted: 08/28/2006

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is **US10/525,244**

Projected Publication Date: Not Applicable

Non-Publication Request: No

**Early Publication Request:** No

**Title**

Single crystal, single crystal wafer, epitaxial wafer, and method of growing single crystal

**Preliminary Class**

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